

PATENT ASSIGNMENT

Electronic Version v1.1
 Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT								
NATURE OF CONVEYANCE:	ASSIGNMENT								
CONVEYING PARTY DATA									
<table border="1"> <thead> <tr> <th>Name</th> <th>Execution Date</th> </tr> </thead> <tbody> <tr> <td>Anup Bhalla</td> <td>08/11/2011</td> </tr> <tr> <td>Xiaobin Wang</td> <td>08/12/2011</td> </tr> <tr> <td>Moses Ho</td> <td>12/09/2011</td> </tr> </tbody> </table>	Name	Execution Date	Anup Bhalla	08/11/2011	Xiaobin Wang	08/12/2011	Moses Ho	12/09/2011	
Name	Execution Date								
Anup Bhalla	08/11/2011								
Xiaobin Wang	08/12/2011								
Moses Ho	12/09/2011								
RECEIVING PARTY DATA									
Name:	Alpha and Omega Semiconductor Incorporated								
Street Address:	475 Oakmead Pkwy								
City:	Sunnyvale								
State/Country:	CALIFORNIA								
Postal Code:	94085								
PROPERTY NUMBERS Total: 1									
<table border="1"> <thead> <tr> <th>Property Type</th> <th>Number</th> </tr> </thead> <tbody> <tr> <td>Application Number:</td> <td>13925776</td> </tr> </tbody> </table>	Property Type	Number	Application Number:	13925776					
Property Type	Number								
Application Number:	13925776								
CORRESPONDENCE DATA									
Fax Number:	6509494118								
<i>Correspondence will be sent via US Mail when the fax attempt is unsuccessful.</i>									
Email:	boinlin@gmail.com								
Correspondent Name:	Bo-In Lin								
Address Line 1:	13445 Mandoli Drive								
Address Line 4:	Los Altos Hills, CALIFORNIA 94022								
ATTORNEY DOCKET NUMBER:	AOS-0811C								
NAME OF SUBMITTER:	Bo-In Lin								
Signature:	/Bo-In Lin/								
Date:	06/27/2013								
Total Attachments: 3 source=AOS-0811D signed assignment#page1.tif source=AOS-0811D signed assignment#page2.tif source=AOS-0811D signed assignment#page3.tif									

CH \$40.00 13925776

ASSIGNMENT

INVENTOR Whereas, I, **Anup Bhalla** of 1406 Block Drive
AND CITY Santa Clara, CA 95050

have invented:

TITLE: **ENHANCING SCHOTTKY BREAKDOWN VOLTAGE (BV) WITHOUT
AFFECTING AN INTEGRATED MOSFET-SCHOTTKY DEVICE LAYOUT**

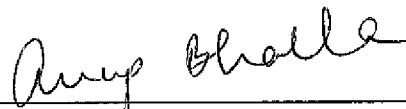
DATE INVENTOR and executed a United States patent application therefor
SIGNED THE
DECLARATION on 8/11, 2011;

Whereas, **Alpha and Omega Semiconductor Incorporated**, a California Company, having its registered address at 475 Oakmead Pkwy, Sunnyvale, CA 94085, USA, (hereinafter called **AOS**), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to **AOS**, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to **AOS** its successors and assigns; and I hereby agree that **AOS** may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND Signed and Sealed at Sunnyvale, California

DATE on 8/11, 2011.



SIGNATURE OF INVENTOR

ASSIGNMENT

INVENTOR Whereas, I, **Xiaobin Wang** of 1770 Widen Court
AND CITY San Jose, CA 95132

have invented:

TITLE: **ENHANCING SCHOTTKY BREAKDOWN VOLTAGE (BV) WITHOUT
AFFECTING AN INTEGRATED MOSFET-SCHOTTKY DEVICE LAYOUT**

DATE INVENTOR and executed a United States patent application therefor
SIGNED THE
DECLARATION on 08/12/2011, 2011;

Whereas, **Alpha and Omega Semiconductor Incorporated**, a California Company, having its registered address at 475 Oakmead Pkwy, Sunnyvale, CA 94085, USA, (hereinafter called **AOS**), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to **AOS**, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to **AOS** its successors and assigns; and I hereby agree that **AOS** may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND Signed and Sealed at Sunnyvale, California

DATE on 08/12, 2011.



SIGNATURE OF INVENTOR

ASSIGNMENT

INVENTOR Whereas, I, **Moses Ho** of 1743 Villarita Dr.
AND CITY Campbell, CA 95008

have invented:

TITLE: **ENHANCING SCHOTTKY BREAKDOWN VOLTAGE (BV) WITHOUT
AFFECTING AN INTEGRATED MOSFET-SCHOTTKY DEVICE LAYOUT**

DATE INVENTOR and executed a United States patent application therefor
SIGNED THE
DECLARATION on Dec 9, 2011;

Whereas, **Alpha and Omega Semiconductor Incorporated**, a California Company, having its registered address at 475 Oakmead Pkwy, Sunnyvale, CA 94085, USA, (hereinafter called **AOS**), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to **AOS**, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to **AOS** its successors and assigns; and I hereby agree that **AOS** may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND Signed and Sealed at Sunnyvale, California

DATE on Dec 9, 2011.


SIGNATURE OF INVENTOR